# 850nm 700mW VCSEL Diode LD0850-B700-0020CA-XXXX

#### **Features**

- 850nm single wavelength
- Low wavelength drift
- Oxide isolation technology
- Low threshold current
- High reliability
- Easy to collimate

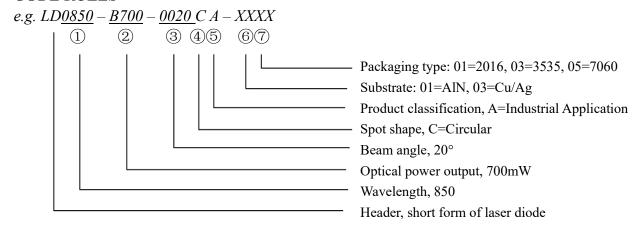
# **Applications**

- 3D sensors
- Lidars
- IR illuminations
- Medical application
- Proximity sensors
- Night vision

#### PRODUCT IDENTIFY

Part Number	Description
LD0850-B700-0020CA-XXXX	850nm 700mW VCSEL Diode

#### **CODE RULES**



# I. Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Case Operating Temp	Тор	-40 to 85	°C
Storage Temp	Tsto	-40 to 105	°C
Reflow Soldering Temperature	Tsdr	240°C(10s)	°C
Reverse Voltage	Vr	5	V
Maximum Continuous Current	Imax	2	A
ESD exposure (Human body) model	ESD	2K	V

#### Note:

- 1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or other conditions above those indicated in the operations section for extended periods of time may affect reliability.
- 2. In its maximum rating diode laser operation could damage its performance or cause potential safety hazard

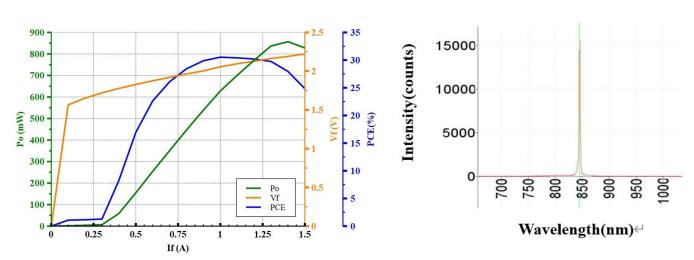
- such as equipment failure.
- 3. Electrostatic discharge is the main reason for the laser fault of the diode. Take effective precautions against ESD. When dealing with laser diodes, use the wrist strap, grounding work surface and strict antistatic technology.

II. Optical-electrical characteristics @25°C

VCSEL P	Parameters	Symbol	Conditions	Min.	Typ.	Max.	Units
Optical Po	wer Output	Po	$I_F = 1.05A$	-	700	-	mW
Thresho	ld Current	$I_{TH}$	-	-	0.1	-	A
Forward	d Current	$I_{\mathrm{F}}$	Po =700 mW		1.05		A
Slope E	Efficiency	η	Po =700 mW	-	0.93	-	W/A
	onversion ciency	PCE	$I_F = mA$		33		%
Peak Wa	avelength	$\lambda_{ m P}$	$I_F = 1.05A$	840	850	860	nm
Laser Forv	vard Voltage	$V_{\rm F}$	$I_F = 1.05A$	-	2.1	-	V
Series R	Lesistance	$R_S$	$I_F = 1.05A$	-	0.84	-	Ohm
Emiss	ion area	-	-	-	470*470	-	um
Beam	(1/e^2)	θ	-	-	20	-	Degrees
Angle	FWHM	θ	-	-	-	-	Degrees
Waveler	ngth shift	$\partial \lambda_P / \partial T$	$I_F = 1.05A$	-	-	0.07	nm/°C
Soldering Temperature		-	AlN	-	-	240(10s)	°C
			Cu/Ag		-	180(10s)	°C
Sub	strate	AIN, Cu/Ag					

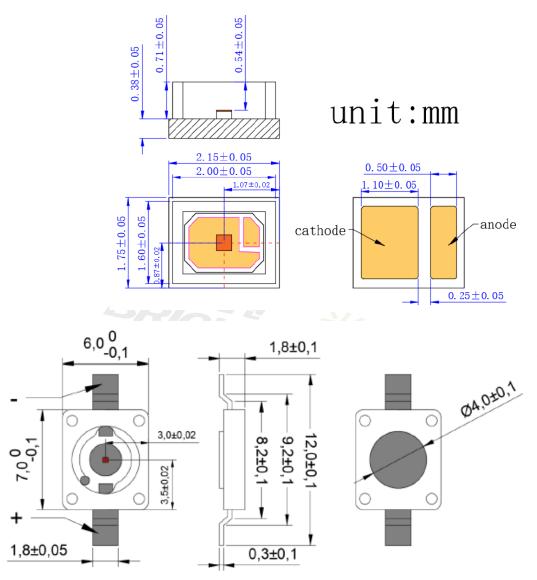
**Note:** Electro-Optical Characteristic with a package or diffuser would require further evaluation. Values are based on limited sample size and estimated values.

# III.LIV Graph and Wavelength

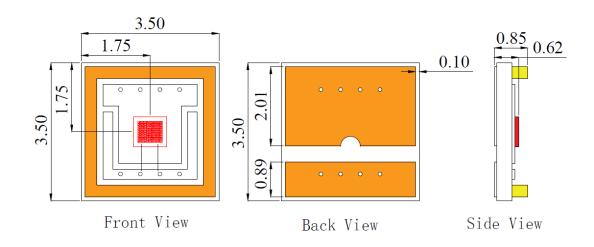


# IV. Mechanical Schematics (unit:mm)

# LD0850-B700-0020CA-0101 (Substrate AIN, Package 2016)

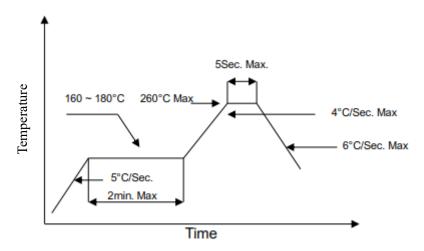


LD0850-B700-0020CA-0305 (Substrate Cu/Ag, Package 7060)



**Note:** There may be some changes between sample and drawing, thus, the actual spec please refer to the sample that you received. And if any question please contact us.

### V. SMT reflow soldering curve



**Note:** Reflow soldering can be operated only one time. During the temperature ramp-up, no forces may be exerted on the LD which could deform or damage them. After soldering completed, please also do not process until the product temperature ramp down to room temperature.

#### VI. Treatment and protection measures

#### **Soldering precautions**

For AlN substrate, the temperature of soldering iron must be controlled under 260°C during manual soldering; for Cu/Ag substrate, the temperature of soldering iron must be controlled under 180°C during manual soldering. Also, VCSEL can be only soldered one time with the soldering time less than 3s. But, It is very hard to control the soldering temperature and homogenize solder paste because of the smaller size of VCSEL. In addition, it is easy to damage VCSEL structure even causes VCSEL losing efficacy. So, we advise you to use re-flow soldering machine for operation.

#### Storage precautions

Our products were sealed by aluminum foil bag attaching packed desiccant, they are moisture proof and anti-static. Please handle these gently to avoid damage. At the same time, please be ready for storage and take some moisture-proof measures to keep VCSEL away from dampness that may causes reliability failure.

Before opening, VCSEL must be kept below 30°C with 60%RH. Recommend for use within 90 days.

After opening, VCSEL must be kept in an environment that temperature lower than 30°C and humidity lower than 60%RH and used up within 24 hours. When the storage humidity reaches and exceeds 60%, the products must be dehumidified at 60°C for more than 24hours before use.

#### **Others**

- 1. Please use solder paste to cure the laser diode.
- 2. Please make sure that the heat of LD has been completely conducted to metal shell, to avoid affecting the optical power output.
- 3. This LD can be only used in constant voltage and current.
- 4. Operating voltage and current, refer to the table in paragraph II.
- 5. Please do not aim the laser to people or animal.
- 6. You can observe the laser spot through an image monitoring equipment.
- 7. Please do not touch LD surface by naked hands or squeeze the sealant on LD surface, or it may cause wrong optical angle and distorted laser spot, even damage the LD.
- 8. Please use ceramic suction nozzle to suck on the LD, so to avoid LD sticking to the nozzle.
- 9. Please add a 0.02s blowing action after locating the laser diode to aluminum substrate.

## VII. Revision history

Revision	Date	Description
V.01	2020/07/15	The first official edition
V.02	2020/09/18	Update spec data and package (0021C1.1)
V.03	2020/11/21	Update spec data (0022C7,0022C8)
V.04	2021/10/20	Update package 3535

<sup>\*\*</sup>BrightPhoton reserves the right to make modification at any time due to improved design from time to time, the merit behind is in order to supply the best product possible.